

Surface Mount

# Monolithic Amplifier

DC-1 GHz

## Features

- InGaP HBT IF and RF amplifier
- Frequency range, DC to 1 GHz
- High gain, 25.1 dB typ. at 0.1 GHz
- Internally Matched to 50 Ohms
- +19.2 dBm typ. output power at 0.1 GHz
- High IP3, +38 dBm at 0.1 GHz
- Low noise figure, 2.7 dB typ.
- Unconditionally stable
- Low thermal resistance
- Transient protected
- Aqueous washable
- Protected by US patent, 6,943,629

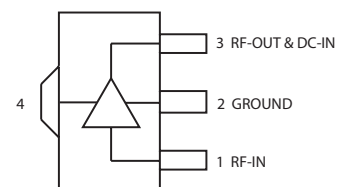
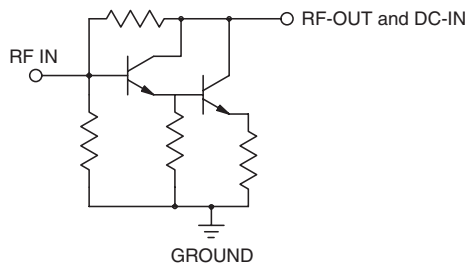
## Applications

- Cellular
- Broadband
- Communication receivers & transmitters

## General Description

Gali $\square$ 74+ (RoHS compliant) is a wideband amplifier offering high dynamic range. Lead finish is SnAgNi. It has repeatable performance from lot to lot, and is enclosed in a SOT-89 package. It uses patented Transient Protected Darlington configuration and is fabricated using InGaP HBT technology. Expected MTBF is 500 years at 85°C case temperature. Gali $\square$ 74+ is designed to be rugged for ESD and supply switch-on transients.

## simplified schematic and pin description



## Gali $\square$ 74+

CASE STYLE: DF782  
PRICE: \$2.35 ea. QTY. (20)

+ RoHS compliant in accordance with EU Directive (2002/95/EC)

The +Suffix has been added in order to identify RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications.

Function	Pin Number	Description
RF IN	1	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
RF-OUT and DC-IN	3	RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit".
GND	2,4	Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance.

**Mini-Circuits**  
ISO 9001 ISO 14001 AS 9100 CERTIFIED

For detailed performance specs & shopping online see web site

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IF/RF MICROWAVE COMPONENTS

Notes: 1. Performance and quality attributes and conditions not expressly stated in this specification sheet are intended to be excluded and do not form a part of this specification sheet. 2. Electrical specifications and performance data contained herein are based on Mini-Circuit's applicable established test performance criteria and measurement instructions. 3. The parts covered by this specification sheet are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at [www.minicircuits.com/MCLStore/terms.jsp](http://www.minicircuits.com/MCLStore/terms.jsp).

REV. D  
M120653  
Gali-74+  
ED-10887/6  
MM/RS/CP/AM  
120307  
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**Electrical Specifications at 25°C and 80mA, unless noted**

Parameter		Min.	Typ.	Max.	Units
Frequency Range*		DC		1	GHz
Gain	f=0.1 GHz		25.1		dB
	f=1 GHz	20	21.8		
	f=2 GHz		18.0		
	f=3 GHz		15.3		
	f=4 GHz		13.4		
Input Return Loss	f= DC to 1 GHz		21		dB
Output Return Loss	f= DC to 1 GHz		12.5		dB
Output Power @ 1 dB compression	f=0.1 GHz	18	19.2		dBm
	f=0.5 GHz		19		
	f=1.0 GHz		18.3		
Output IP3	f=0.1 GHz		38		dBm
	f=0.5 GHz		37		
	f=1.0 GHz		33		
Noise Figure			2.7		dB
Recommended Device Operating Current			80		mA
Device Operating Voltage		4.3	4.8	5.3	V
Device Voltage Variation vs. Temperature at 80 mA			-3.1		mV/°C
Device Voltage Variation vs. Current at 25°C			2.8		mV/mA
Thermal Resistance, junction-to-case <sup>1</sup>			120		°C/W

\*Guaranteed specification DC-1 GHz. Low frequency cut off determined by external coupling capacitors.

**Absolute Maximum Ratings**

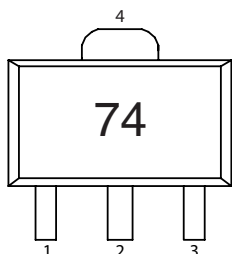
Parameter	Ratings
Operating Temperature*	-45°C to 85°C
Storage Temperature	-65°C to 150°C
Operating Current	130mA
Input Power	10dBm

Note: Permanent damage may occur if any of these limits are exceeded. These ratings are not intended for continuous normal operation.

\*Case is defined as ground leads.

<sup>1</sup>Based on typical case temperature rise 6°C above ambient.

**Product Marking**



Markings in addition to model number designation may appear for internal quality control purposes.

**Additional Detailed Technical Information**

Additional information is available on our web site. To access this information enter the model number on our web site home page.

**Performance data, graphs, s-parameter data set (.zip file)**

**Case Style: DF782**

Plastic package, exposed paddle, lead finish: tin/silver/nickel

**Tape & Reel: F55**

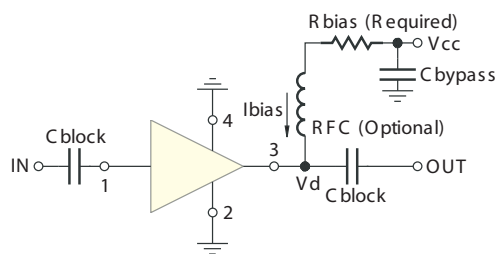
7" reels with 20, 50, 100, 200, 500, 1K devices.

**Suggested Layout for PCB Design: PL-019**

**Evaluation Board: TB-409-74+**

**Environmental Ratings: ENV08T2**

**Recommended Application Circuit**



Test Board includes case, connectors, and components (in bold) soldered to PCB

R BIAS	
Vcc	"1%" Res. Values (ohms) for Optimum Biasing
7	28.7
8	41.2
9	53.6
10	66.5
11	78.7
12	90.9
13	102
14	115
15	127

**ESD Rating**

Human Body Model (HBM): Class 1C (1000v to < 2000v) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M2 (100v to < 200v) in accordance with ANSI/ESD STM 5.2 - 1999

**MSL Rating**

Moisture Sensitivity: MSL1 in accordance with IPC/JEDECJ-STD-020C

No.	Test Required	Condition	Standard	Quantity
1	Visual Inspection	Low Power Microscope Magnification 40x	MIP-IN-0003 (MCT spec)	45 units
2	Electrical Test	Room Temperature	SCD (MCL spec)	45 units
3	SAM Analysis	Less than 10% growth in term of delamination	J-Std-020C (Jedec Standard)	45 units
4	Moisture Sensitivity Level 1	Bake at 125°C for 24 hours Soak at 85°C/85%RH for 168 hours Reflow 3 cycles at 260°C peak	J-Std-020C (Jedec Standard)	45 units

**MSL Test Flow Chart**

